

1. General description

Dual ultrafast power diode in a SOT78 (TO-220AB) plastic package.

2. Features and benefits

- Fast switching
- Low thermal resistance
- High thermal cycling performance
- Low forward voltage drop
- Reverse surge capability
- Soft recovery characteristic

3. Applications

- Output rectifiers in high-frequency switched-mode power supplies

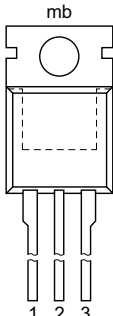
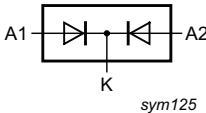
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values				Unit
Absolute maximum rating							
V _{RRM}	repetitive peak reverse voltage		200				V
I _{O(AV)}	average output current	δ = 0.5; square-wave pulse; T _{mb} ≤ 104 °C; both diodes conducting; Fig. 1 ; Fig. 2	16				A
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _{mb} ≤ 104 °C; square-wave pulse; per diode	16				A
I _{FSM}	non-repetitive peak forward current	t _p = 10 ms; sine-wave pulse; per diode T _{J(init)} = 25 °C	80				A
		t _p = 8.3 ms; sine-wave pulse; per diode T _{J(init)} = 25 °C	88				A
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
V _F	forward voltage	I _F = 8 A; T _J = 150 °C; Fig. 4		-	0.84	0.95	V
Dynamic characteristics							
t _{rr}	reverse recovery time	I _R = 1 A; I _F = 0.5 A; I _{R(meas)} = 0.25 A; T _J = 25 °C; step recovery; Fig. 6		-	12	22	ns

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1		
2	K	cathode		
3	A2	anode 2		
mb	K	mounting base; cathode		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BYQ30E-200	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78

7. Marking

Table 4. Marking codes

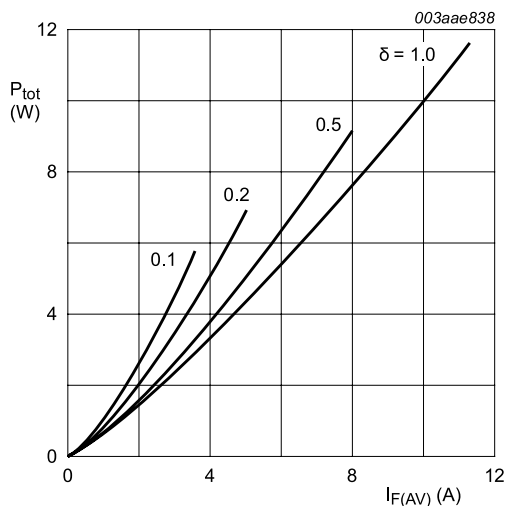
Type number	Marking codes
BYQ30E-200	BYQ30E-200

8. Limiting values

Table 5. Limiting values

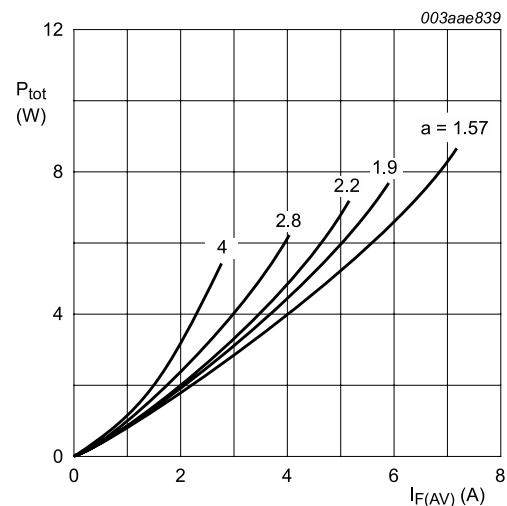
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		200	V
V_{RWM}	crest working reverse voltage		200	V
V_R	reverse voltage	DC	200	V
$I_{O(AV)}$	average output current	$\delta = 0.5$; square-wave pulse; $T_{mb} \leq 104\text{ }^{\circ}\text{C}$; both diodes conducting; Fig. 1 ; Fig. 2	16	A
I_{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25\text{ }\mu\text{s}$; $T_{mb} \leq 104\text{ }^{\circ}\text{C}$; square-wave pulse; per diode	16	A
I_{FSM}	non-repetitive peak forward current	$t_p = 10\text{ ms}$; sine-wave pulse; per diode $T_{j(\text{init})} = 25\text{ }^{\circ}\text{C}$	80	A
		$t_p = 8.3\text{ ms}$; sine-wave pulse; per diode $T_{j(\text{init})} = 25\text{ }^{\circ}\text{C}$	88	A
I_{RRM}	repetitive peak reverse current	$\delta = 0.001$; $t_p = 2\text{ }\mu\text{s}$	0.2	A
I_{RSM}	non-repetitive peak reverse current	$t_p = 100\text{ }\mu\text{s}$	0.2	A
T_{stg}	storage temperature		-40 to 150	$^{\circ}\text{C}$
T_j	junction temperature		150	$^{\circ}\text{C}$
Electrostatic discharge				
V_{ESD}	electrostatic discharge voltage	HBM; all pins; $C = 250\text{ pF}$; $R = 1.5\text{ k}\Omega$	8	kV



$$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



$$a = \text{form factor} = I_{F(RMS)} / I_{F(AV)}$$

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	with heatsink compound; both diodes conducting; Fig. 3		-	-	2.5	K/W
		with heatsink compound; per diode; Fig. 3		-	-	3	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient			-	60	-	K/W

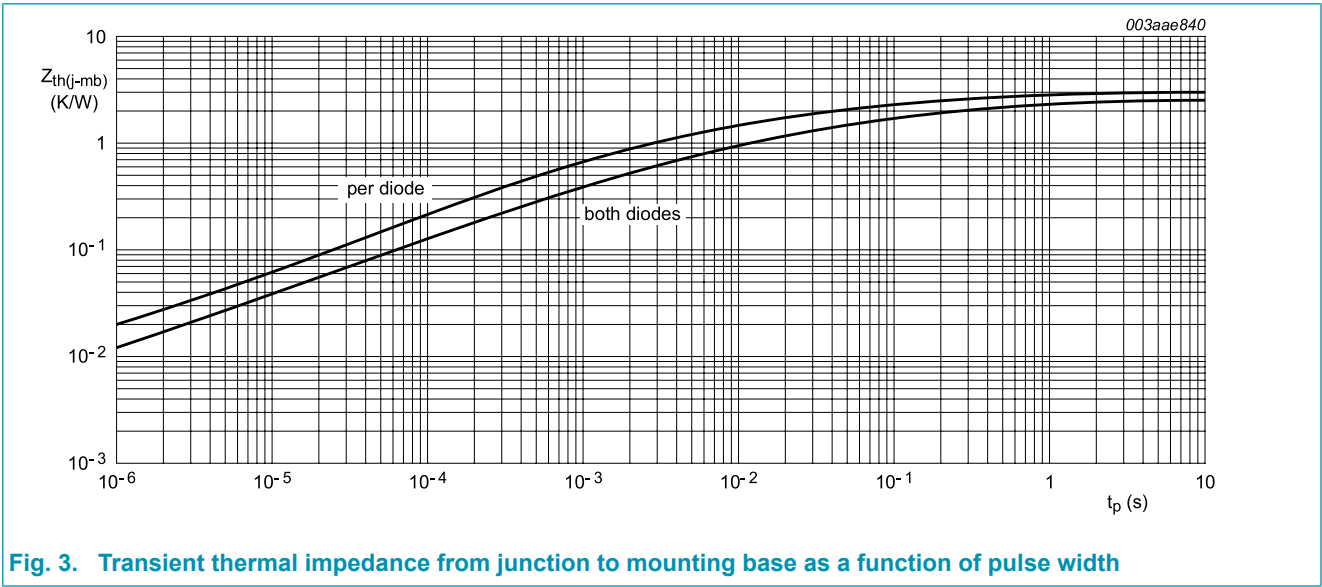
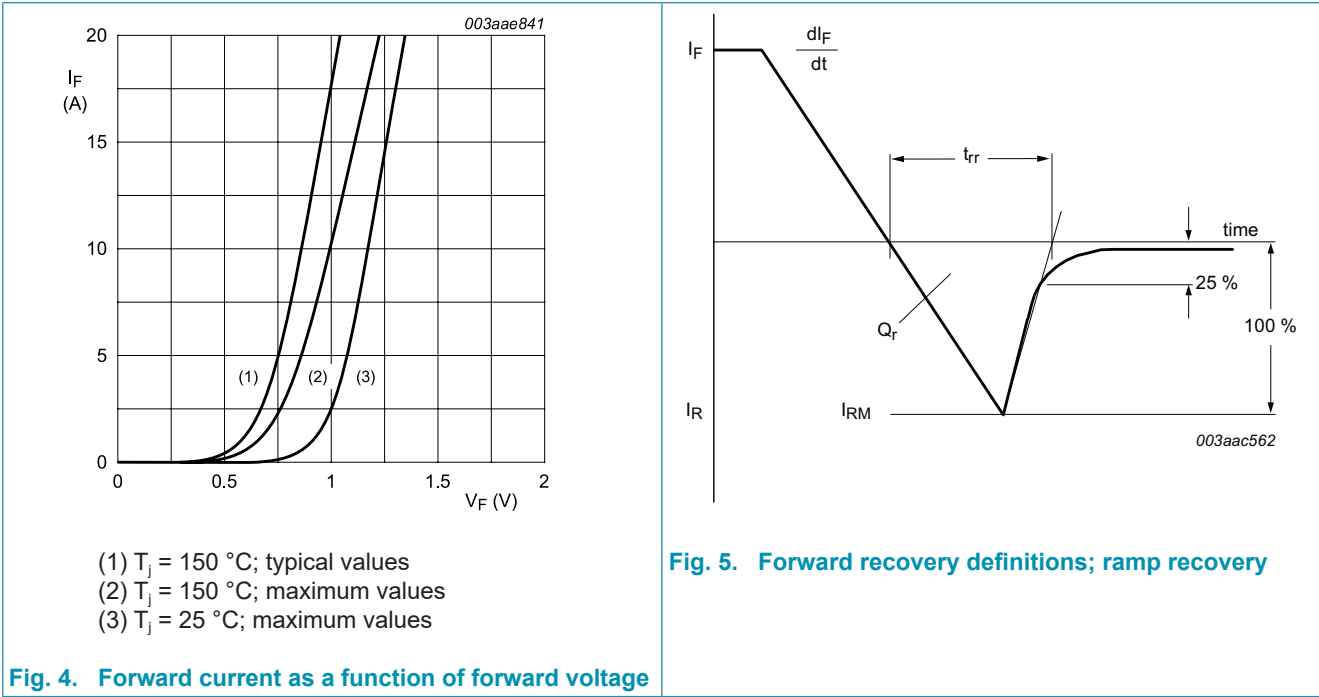


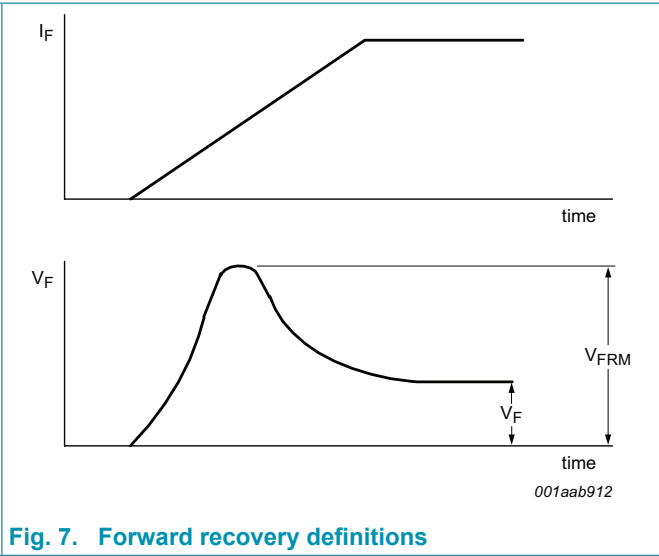
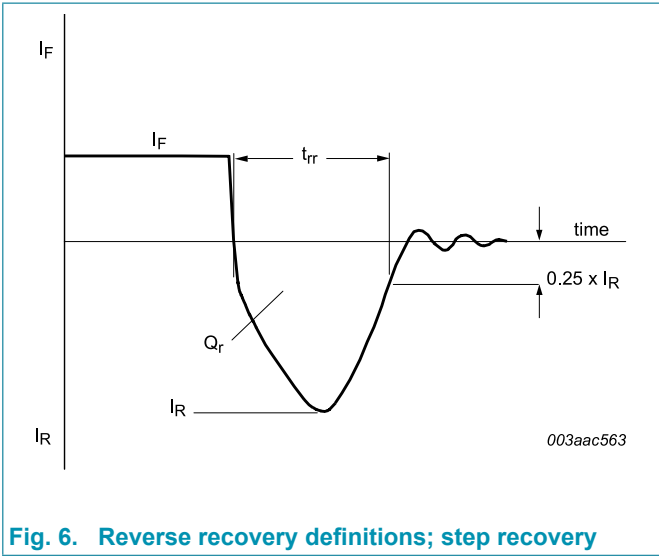
Fig. 3. Transient thermal impedance from junction to mounting base as a function of pulse width

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
V _F	forward voltage	I _F = 16 A; T _j = 150 °C; Fig. 4		-	1	1.15	V
		I _F = 16 A; T _j = 25 °C; Fig. 4		-	1.12	1.25	V
		I _F = 8 A; T _j = 150 °C; Fig. 4		-	0.84	0.95	V
I _R	reverse current	V _R = 200 V; T _j = 25 °C		-	4	30	μA
		V _R = 200 V; T _j = 100 °C		-	0.3	0.6	mA
Dynamic characteristics							
Q _r	recovered charge	I _F = 2 A; V _R = 30 V; dI _F /dt = 20 A/μs; T _j = 25 °C; Fig. 5		-	4	11	nC
t _{rr}	reverse recovery time	I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/μs; ramp recovery; T _j = 25 °C; Fig. 5		-	20	25	ns
		I _F = 0.5 A; I _R = 1 A; step recovery; I _{R(meas)} = 0.25 A; T _j = 25 °C; Fig. 6		-	12	22	ns
V _{FR}	forward recovery voltage	I _F = 1 A; dI _F /dt = 10 A/μs; T _j = 25 °C; Fig. 7		-	1	-	V

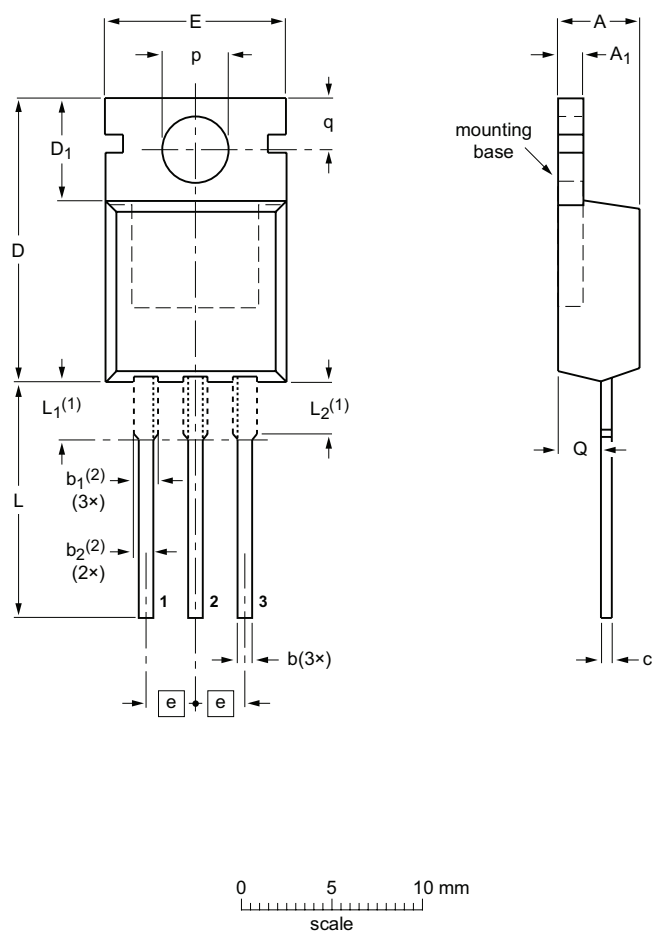




11. Package outline

Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB

SOT78



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁	b	b ₁ (2)	b ₂ (2)	c	D	D ₁	E	e	L	L ₁ (1)	L ₂ (1) max.	p	q	Q
mm	4.7 4.1	1.40 1.25	0.9 0.6	1.6 1.0	1.3 1.0	0.7 0.4	16.0 15.2	6.6 5.9	10.3 9.7	2.54	15.0 12.8	3.30 2.79	3.0	3.8 3.5	3.0 2.7	2.6 2.2

- Notes
- 1. Lead shoulder designs may vary.
 - 2. Dimension includes excess dambar.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT78		3-lead TO-220AB	SC-46			08-04-23 08-06-13

12. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BYQ30E-200 v.5	20180605	Product data sheet	-	BYQ30E-200 v.4
Modifications:	Change from NXP version to WeEn version			
BYQ30E-200 v.4	20100901	Product data sheet	-	BYQ30E_SERIES_3
Modifications:	• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. • Legal texts have been adapted to the new company name where appropriate. • Type number BYQ30E-200 separated from datasheet BYQ30E_SERIES.			
BYQ30E_SERIES_3	19981001	Product specification	-	BYQ30E_SERIES_2

13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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